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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	32MHz
Connectivity	I <sup>2</sup> C, IrDA, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I <sup>2</sup> S, POR, PWM, WDT
Number of I/O	37
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	6K x 8
RAM Size	20K x 8
Voltage - Supply (Vcc/Vdd)	1.65V ~ 3.6V
Data Converters	A/D 13x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-LQFP
Supplier Device Package	48-LQFP (7x7)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/stmicroelectronics/stm32l071cbt6tr">https://www.e-xfl.com/product-detail/stmicroelectronics/stm32l071cbt6tr</a>

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## 2.2 Ultra-low-power device continuum

The ultra-low-power family offers a large choice of core and features, from 8-bit proprietary core up to ARM® Cortex®-M4, including ARM® Cortex®-M3 and ARM® Cortex®-M0+. The STM32Lx series are the best choice to answer your needs in terms of ultra-low-power features. The STM32 ultra-low-power series are the best solution for applications such as gaz/water meter, keyboard/mouse or fitness and healthcare application. Several built-in features like LCD drivers, dual-bank memory, low-power run mode, operational amplifiers, 128-bit AES, DAC, crystal-less USB and many other definitely help you building a highly cost optimized application by reducing BOM cost. STMicroelectronics, as a reliable and long-term manufacturer, ensures as much as possible pin-to-pin compatibility between all STM8Lx and STM32Lx on one hand, and between all STM32Lx and STM32Fx on the other hand. Thanks to this unprecedented scalability, your legacy application can be upgraded to respond to the latest market feature and efficiency requirements.

## 3 Functional overview

### 3.1 Low-power modes

The ultra-low-power STM32L071xx support dynamic voltage scaling to optimize its power consumption in Run mode. The voltage from the internal low-drop regulator that supplies the logic can be adjusted according to the system's maximum operating frequency and the external voltage supply.

There are three power consumption ranges:

- Range 1 ( $V_{DD}$  range limited to 1.71-3.6 V), with the CPU running at up to 32 MHz
- Range 2 (full  $V_{DD}$  range), with a maximum CPU frequency of 16 MHz
- Range 3 (full  $V_{DD}$  range), with a maximum CPU frequency limited to 4.2 MHz

Seven low-power modes are provided to achieve the best compromise between low-power consumption, short startup time and available wakeup sources:

- **Sleep mode**

In Sleep mode, only the CPU is stopped. All peripherals continue to operate and can wake up the CPU when an interrupt/event occurs. Sleep mode power consumption at 16 MHz is about 1 mA with all peripherals off.

- **Low-power run mode**

This mode is achieved with the multispeed internal (MSI) RC oscillator set to the low-speed clock (max 131 kHz), execution from SRAM or Flash memory, and internal regulator in low-power mode to minimize the regulator's operating current. In Low-power run mode, the clock frequency and the number of enabled peripherals are both limited.

- **Low-power sleep mode**

This mode is achieved by entering Sleep mode with the internal voltage regulator in low-power mode to minimize the regulator's operating current. In Low-power sleep mode, both the clock frequency and the number of enabled peripherals are limited; a typical example would be to have a timer running at 32 kHz.

When wakeup is triggered by an event or an interrupt, the system reverts to the Run mode with the regulator on.

**Stop mode with RTC**

The Stop mode achieves the lowest power consumption while retaining the RAM and register contents and real time clock. All clocks in the  $V_{CORE}$  domain are stopped, the PLL, MSI RC, HSE crystal and HSI RC oscillators are disabled. The LSE or LSI is still running. The voltage regulator is in the low-power mode.

Some peripherals featuring wakeup capability can enable the HSI RC during Stop mode to detect their wakeup condition.

The device can be woken up from Stop mode by any of the EXTI line, in 3.5  $\mu$ s, the processor can serve the interrupt or resume the code. The EXTI line source can be any GPIO. It can be the PVD output, the comparator 1 event or comparator 2 event (if internal reference voltage is on), it can be the RTC alarm/tamper/timestamp/wakeup events, the USART/I2C/LPUART/LPTIMER wakeup events.

- **Stop mode without RTC**

The Stop mode achieves the lowest power consumption while retaining the RAM and register contents. All clocks are stopped, the PLL, MSI RC, HSI and LSI RC, HSE and LSE crystal oscillators are disabled.

Some peripherals featuring wakeup capability can enable the HSI RC during Stop mode to detect their wakeup condition.

The voltage regulator is in the low-power mode. The device can be woken up from Stop mode by any of the EXTI line, in 3.5  $\mu$ s, the processor can serve the interrupt or resume the code. The EXTI line source can be any GPIO. It can be the PVD output, the comparator 1 event or comparator 2 event (if internal reference voltage is on). It can also be wakened by the USART/I2C/LPUART/LPTIMER wakeup events.

- **Standby mode with RTC**

The Standby mode is used to achieve the lowest power consumption and real time clock. The internal voltage regulator is switched off so that the entire  $V_{CORE}$  domain is powered off. The PLL, MSI RC, HSE crystal and HSI RC oscillators are also switched off. The LSE or LSI is still running. After entering Standby mode, the RAM and register contents are lost except for registers in the Standby circuitry (wakeup logic, IWDG, RTC, LSI, LSE Crystal 32 KHz oscillator, RCC\_CSR register).

The device exits Standby mode in 60  $\mu$ s when an external reset (NRST pin), an IWDG reset, a rising edge on one of the three WKUP pins, RTC alarm (Alarm A or Alarm B), RTC tamper event, RTC timestamp event or RTC Wakeup event occurs.

- **Standby mode without RTC**

The Standby mode is used to achieve the lowest power consumption. The internal voltage regulator is switched off so that the entire  $V_{CORE}$  domain is powered off. The PLL, MSI RC, HSI and LSI RC, HSE and LSE crystal oscillators are also switched off. After entering Standby mode, the RAM and register contents are lost except for registers in the Standby circuitry (wakeup logic, IWDG, RTC, LSI, LSE Crystal 32 KHz oscillator, RCC\_CSR register).

The device exits Standby mode in 60  $\mu$ s when an external reset (NRST pin) or a rising edge on one of the three WKUP pin occurs.

*Note: The RTC, the IWDG, and the corresponding clock sources are not stopped automatically by entering Stop or Standby mode.*

**Table 3. Functionalities depending on the operating power supply range**

Operating power supply range	Functionalities depending on the operating power supply range		
	ADC operation	Dynamic voltage scaling range	I/O operation
$V_{DD} = 1.65$ to $1.71$ V	ADC only, conversion time up to 570 ksps	Range 2 or range 3	Degraded speed performance
$V_{DD} = 1.71$ to $1.8$ V <sup>(1)</sup>	ADC only, conversion time up to 1.14 Msps	Range 1, range 2 or range 3	Degraded speed performance
$V_{DD} = 1.8$ to $2.0$ V <sup>(1)</sup>	Conversion time up to 1.14 Msps	Range1, range 2 or range 3	Degraded speed performance

**Table 5. Functionalities depending on the working mode  
(from Run/active down to standby) (continued)<sup>(1)(2)</sup>**

IPs	Run/Active	Sleep	Low-power run	Low-power sleep	Stop	Standby
					Wakeup capability	Wakeup capability
Consumption $V_{DD}=1.8$ to $3.6$ V (Typ)	Down to $140\text{ }\mu\text{A/MHz}$ (from Flash memory)	Down to $37\text{ }\mu\text{A/MHz}$ (from Flash memory)	Down to $8\text{ }\mu\text{A}$	Down to $4.5\text{ }\mu\text{A}$	$0.4\text{ }\mu\text{A}$ (No RTC) $V_{DD}=1.8\text{ V}$	$0.28\text{ }\mu\text{A}$ (No RTC) $V_{DD}=1.8\text{ V}$
					$0.8\text{ }\mu\text{A}$ (with RTC) $V_{DD}=1.8\text{ V}$	$0.65\text{ }\mu\text{A}$ (with RTC) $V_{DD}=1.8\text{ V}$
					$0.4\text{ }\mu\text{A}$ (No RTC) $V_{DD}=3.0\text{ V}$	$0.29\text{ }\mu\text{A}$ (No RTC) $V_{DD}=3.0\text{ V}$
					$1\text{ }\mu\text{A}$ (with RTC) $V_{DD}=3.0\text{ V}$	$0.85\text{ }\mu\text{A}$ (with RTC) $V_{DD}=3.0\text{ V}$

- Legend:  
 "Y" = Yes (enable).  
 "O" = Optional can be enabled/disabled by software  
 "-" = Not available
- The consumption values given in this table are preliminary data given for indication. They are subject to slight changes.
- Some peripherals with wakeup from Stop capability can request HSI to be enabled. In this case, HSI is woken up by the peripheral, and only feeds the peripheral which requested it. HSI is automatically put off when the peripheral does not need it anymore.
- UART and LPUART reception is functional in Stop mode. It generates a wakeup interrupt on Start. To generate a wakeup on address match or received frame event, the LPUART can run on LSE clock while the UART has to wake up or keep running the HSI clock.
- I2C address detection is functional in Stop mode. It generates a wakeup interrupt in case of address match. It will wake up the HSI during reception.

## 3.2 Interconnect matrix

Several peripherals are directly interconnected. This allows autonomous communication between peripherals, thus saving CPU resources and power consumption. In addition, these hardware connections allow fast and predictable latency.

Depending on peripherals, these interconnections can operate in Run, Sleep, Low-power run, Low-power sleep and Stop modes.

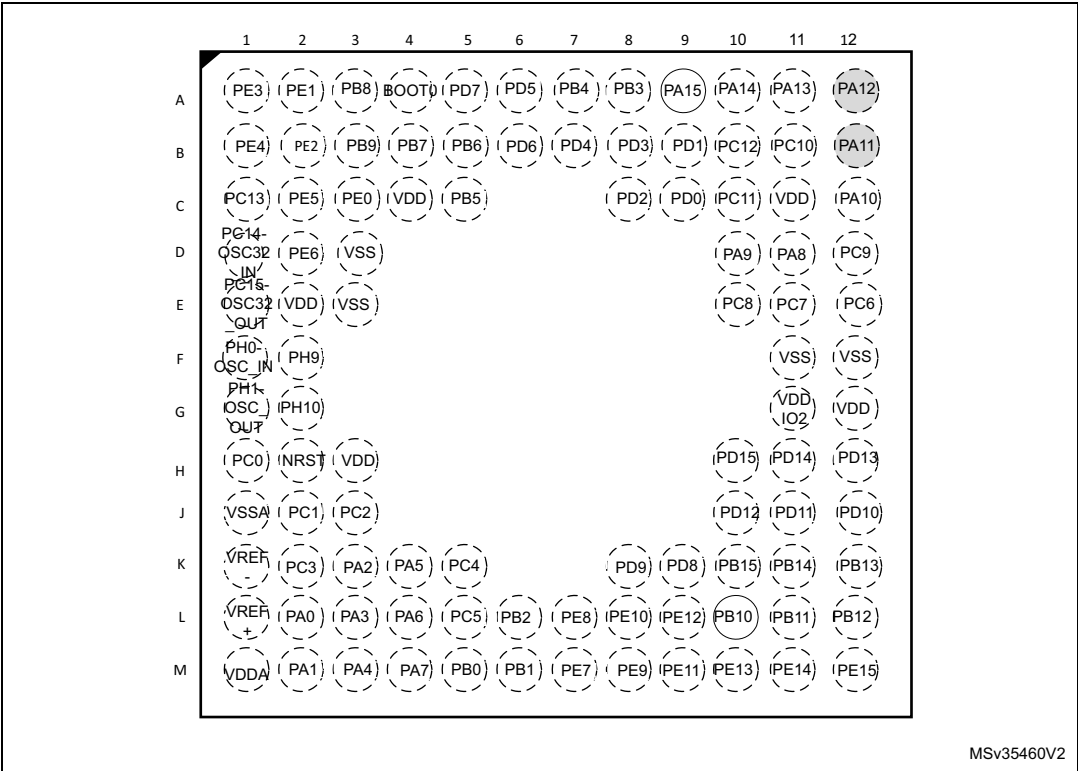
**Table 6. STM32L0xx peripherals interconnect matrix**

Interconnect source	Interconnect destination	Interconnect action	Run	Sleep	Low-power run	Low-power sleep	Stop
COMPx	TIM2, TIM21, TIM22	Timer input channel, trigger from analog signals comparison	Y	Y	Y	Y	-
	LPTIM	Timer input channel, trigger from analog signals comparison	Y	Y	Y	Y	Y
TIMx	TIMx	Timer triggered by other timer	Y	Y	Y	Y	-

- 32.768 kHz low-speed external crystal (LSE)
- 37 kHz low-speed internal RC (LSI), also used to drive the independent watchdog. The LSI clock can be measured using the high-speed internal RC oscillator for greater precision.
- **RTC clock source**  
The LSI, LSE or HSE sources can be chosen to clock the RTC, whatever the system clock.
- **Startup clock**  
After reset, the microcontroller restarts by default with an internal 2.1 MHz clock (MSI). The prescaler ratio and clock source can be changed by the application program as soon as the code execution starts.
- **Clock security system (CSS)**  
This feature can be enabled by software. If an HSE clock failure occurs, the master clock is automatically switched to HSI and a software interrupt is generated if enabled. Another clock security system can be enabled, in case of failure of the LSE it provides an interrupt or wakeup event which is generated if enabled.
- **Clock-out capability (MCO: microcontroller clock output)**  
It outputs one of the internal clocks for external use by the application.

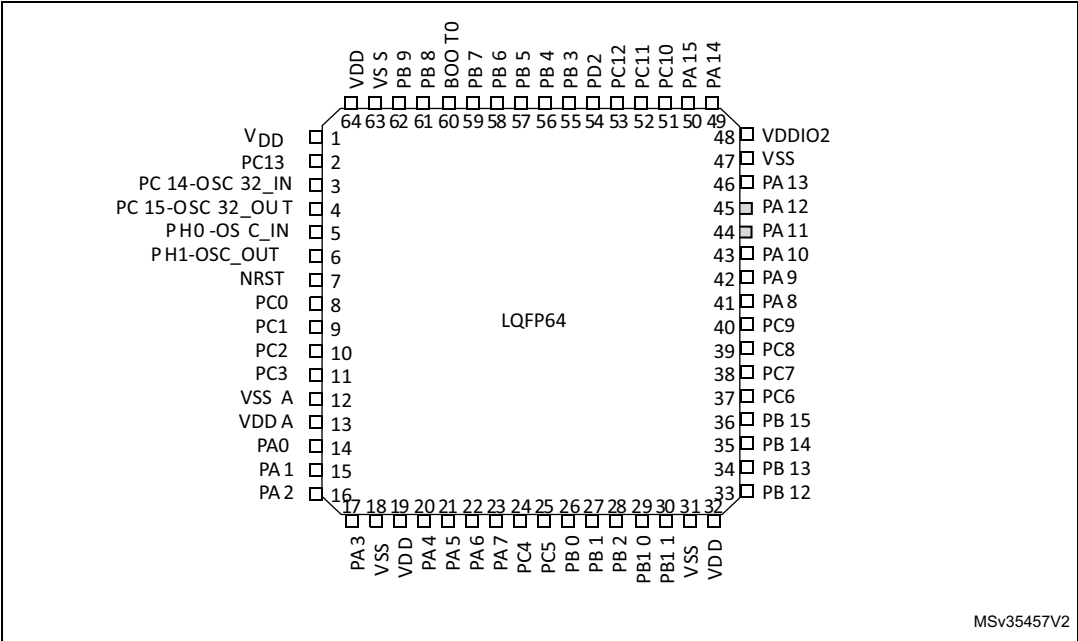
Several prescalers allow the configuration of the AHB frequency, each APB (APB1 and APB2) domains. The maximum frequency of the AHB and the APB domains is 32 MHz. See [Figure 2](#) for details on the clock tree.

Figure 4. STM32L071xx UFBGA100 ballout - 7x 7 mm



1. The above figure shows the package top view.
2. I/O supplied by VDDIO2.

Figure 5. STM32L071xx LQFP64 pinout - 10 x 10 mm



1. The above figure shows the package top view.
2. I/O supplied by VDDIO2.



Table 17. Alternate functions port B

Port		AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7
		SPI1/SPI2/I2S2/ USART1/2/ LPUART1/ LPTIM1/ TIM2/21/22/ EVENTOUT/ SYS_AF	SPI1/SPI2/I2S2/I 2C1/TIM2/21	SPI1/SPI2/I2S2/ LPUART1/ USART5/LPTIM 1/TIM2/3/EVENT OUT/ SYS_AF	I2C1/ EVENTOUT	I2C1/USART1/2/ LPUART1/ TIM3/22/ EVENTOUT	SPI2/I2S2/I2C2/ USART1/ TIM2/21/22	I2C1/2/ LPUART1/ USART4/ UASRT5/TIM21/ EVENTOUT	I2C3/LPUART1/ COMP1/2/ TIM3
Port B	PB0	EVENTOUT		TIM3_CH3		-	-	-	-
	PB1	-		TIM3_CH4		LPUART1_RTS_DE	-	-	-
	PB2	-	-	LPTIM1_OUT		-	-	-	I2C3_SMBA
	PB3	SPI1_SCK		TIM2_CH2		EVENTOUT	USART1_RTS_DE	USART5_TX	-
	PB4	SPI1_MISO		TIM3_CH1		TIM22_CH1	USART1_CTS	USART5_RX	I2C3_SDA
	PB5	SPI1_MOSI		LPTIM1_IN1	I2C1_SMBA	TIM3_CH2/ TIM22_CH2	USART1_CK	USART5_CK/ USART5_RTS_D E	-
	PB6	USART1_TX	I2C1_SCL	LPTIM1_ETR		-	-	-	-
	PB7	USART1_RX	I2C1_SDA	LPTIM1_IN2		-	-	USART4_CTS	-
	PB8	-		-		I2C1_SCL	-	-	-
	PB9	-		EVENTOUT	-	I2C1_SDA	SPI2_NSS/ I2S2_WS	-	-
	PB10	-		TIM2_CH3		LPUART1_TX	SPI2_SCK	I2C2_SCL	LPUART1_RX
	PB11	EVENTOUT		TIM2_CH4		LPUART1_RX	-	I2C2_SDA	LPUART1_TX
	PB12	SPI2_NSS/I2S2_WS		LPUART1_RTS_ DE			I2C2_SMBA	EVENTOUT	-
	PB13	SPI2_SCK/I2S2_CK		MCO		LPUART1_CTS	I2C2_SCL	TIM21_CH1	-
	PB14	SPI2_MISO/ I2S2_MCK		RTC_OUT		LPUART1_RTS_DE	I2C2_SDA	TIM21_CH2	-
	PB15	SPI2_MOSI/ I2S2_SD		RTC_REFIN	-	-	-	-	-



Table 20. Alternate functions port E

Port		AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7
		SPI1/SPI2/I2S2/ USART1/2/ LPUART1/LPTI M1/ TIM2/21/22/ EVENTOUT/ SYS_AF	SPI1/SPI2/I2S2/I2C1 /TIM2/21	SPI1/SPI2/I2S2/ LPUART1/ USART5/ LPTIM1/TIM2/3 /EVENTOUT/ SYS_AF	I2C1/ EVENTOUT	I2C1/USART1/2/ LPUART1/ TIM3/22/ EVENTOUT	SPI2/I2S2 /I2C2/ USART1/ TIM2/21/22	I2C1/2/ LPUART1/ USART4/ UASRT5/TIM21/ EVENTOUT	I2C3/LPUART1/ COMP1/2/TIM3
Port E	PE0	-		EVENTOUT	-	-	-	-	-
	PE1	-		EVENTOUT	-	-	-	-	-
	PE2	-		TIM3_ETR	-	-	-	-	-
	PE3	TIM22_CH1		TIM3_CH1	-	-	-	-	-
	PE4	TIM22_CH2	-	TIM3_CH2	-	-	-	-	-
	PE5	TIM21_CH1	-	TIM3_CH3	-	-	-	-	-
	PE6	TIM21_CH2	-	TIM3_CH4	-	-	-	-	-
	PE7	-		-	-	-	-	USART5_CK/U SART5_RTS_D E	-
	PE8	-		-	-	-	-	USART4_TX	-
	PE9	TIM2_CH1		TIM2_ETR	-	-	-	USART4_RX	-
	PE10	TIM2_CH2		-	-	-	-	USART5_TX	-
	PE11	TIM2_CH3	-	-	-	-	-	USART5_RX	-
	PE12	TIM2_CH4	-	SPI1_NSS	-	-	-	-	-
	PE13	-		SPI1_SCK	-	-	-	-	-
	PE14	-		SPI1_MISO	-	-	-	-	-
	PE15	-		SPI1_MOSI	-	-	-	-	-

## 6.3 Operating conditions

### 6.3.1 General operating conditions

Table 25. General operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
$f_{HCLK}$	Internal AHB clock frequency	-	0	32	MHz
$f_{PCLK1}$	Internal APB1 clock frequency	-	0	32	
$f_{PCLK2}$	Internal APB2 clock frequency	-	0	32	
$V_{DD}$	Standard operating voltage	BOR detector disabled	1.65	3.6	V
		BOR detector enabled, at power on	1.8	3.6	
		BOR detector disabled, after power on	1.65	3.6	
$V_{DDA}$	Analog operating voltage (all features)	Must be the same voltage as $V_{DD}^{(1)}$	1.65	3.6	V
$V_{DDIO2}$	Standard operating voltage	-	1.65	3.6	V
$V_{IN}$	Input voltage on FT, FTf and RST pins <sup>(2)</sup>	$2.0\text{ V} \leq V_{DD} \leq 3.6\text{ V}$	-0.3	5.5	V
		$1.65\text{ V} \leq V_{DD} \leq 2.0\text{ V}$	-0.3	5.2	
	Input voltage on BOOT0 pin	-	0	5.5	
	Input voltage on TC pin	-	-0.3	$V_{DD}+0.3$	
$P_D$	Power dissipation at $T_A = 85\text{ °C}$ (range 6) or $T_A = 105\text{ °C}$ (range 7) <sup>(3)</sup>	UFBGA100 package	-	351	mW
		LQFP100 package	-	488	
		TFBGA64 package	-	313	
		LQFP64 package	-	435	
		WLCSP49 package	-	417	
		LQFP48 package	-	370	
		UFQFPN32 package	-	556	
		LQFP32 package	-	333	
	Power dissipation at $T_A = 125\text{ °C}$ (range 3) <sup>(3)</sup>	UFBGA100 package	-	88	
		LQFP100 package	-	122	
		TFBGA64 package	-	78	
		LQFP64 package	-	109	
		WLCSP49 package	-	104	
		LQFP48 package	-	93	
		UFQFPN32 package	-	139	
		LQFP32 package	-	83	

Table 25. General operating conditions (continued)

Symbol	Parameter	Conditions	Min	Max	Unit
T <sub>A</sub>	Temperature range	Maximum power dissipation (range 6)	−40	85	°C
		Maximum power dissipation (range 7)	−40	105	
		Maximum power dissipation (range 3)	−40	125	
T <sub>J</sub>	Junction temperature range (range 6)	$-40\text{ °C} \leq T_A \leq 85\text{ °}$	−40	105	
	Junction temperature range (range 7)	$-40\text{ °C} \leq T_A \leq 105\text{ °C}$	−40	125	
	Junction temperature range (range 3)	$-40\text{ °C} \leq T_A \leq 125\text{ °C}$	−40	130	

1. It is recommended to power V<sub>DD</sub> and V<sub>DDA</sub> from the same source. A maximum difference of 300 mV between V<sub>DD</sub> and V<sub>DDA</sub> can be tolerated during power-up and normal operation.
2. To sustain a voltage higher than V<sub>DD</sub>+0.3V, the internal pull-up/pull-down resistors must be disabled.
3. If T<sub>A</sub> is lower, higher P<sub>D</sub> values are allowed as long as T<sub>J</sub> does not exceed T<sub>J</sub> max (see [Table 24: Thermal characteristics on page 56](#)).

Table 28. Embedded internal reference voltage<sup>(1)</sup> (continued)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_{LPBUF}^{(4)}$	Consumption of reference voltage buffer for VREF_OUT and COMP	-	-	730	1200	nA
$V_{REFINT\_DIV1}^{(4)}$	1/4 reference voltage	-	24	25	26	% $V_{REFINT}$
$V_{REFINT\_DIV2}^{(4)}$	1/2 reference voltage	-	49	50	51	
$V_{REFINT\_DIV3}^{(4)}$	3/4 reference voltage	-	74	75	76	

1. Refer to [Table 40: Peripheral current consumption in Stop and Standby mode](#) for the value of the internal reference current consumption ( $I_{REFINT}$ ).
2. Guaranteed by test in production.
3. The internal  $V_{REF}$  value is individually measured in production and stored in dedicated EEPROM bytes.
4. Guaranteed by design.
5. Shortest sampling time can be determined in the application by multiple iterations.
6. To guarantee less than 1% VREF\_OUT deviation.

### 6.3.4 Supply current characteristics

The current consumption is a function of several parameters and factors such as the operating voltage, temperature, I/O pin loading, device software configuration, operating frequencies, I/O pin switching rate, program location in memory and executed binary code. The current consumption is measured as described in [Figure 15: Current consumption measurement scheme](#).

All Run-mode current consumption measurements given in this section are performed with a reduced code that gives a consumption equivalent to Dhrystone 2.1 code if not specified otherwise.

The current consumption values are derived from the tests performed under ambient temperature and  $V_{DD}$  supply voltage conditions summarized in [Table 25: General operating conditions](#) unless otherwise specified.

The MCU is placed under the following conditions:

- All I/O pins are configured in analog input mode
- All peripherals are disabled except when explicitly mentioned
- The Flash memory access time and prefetch is adjusted depending on fHCLK frequency and voltage range to provide the best CPU performance unless otherwise specified.
- When the peripherals are enabled  $f_{APB1} = f_{APB2} = f_{APB}$
- When PLL is on, the PLL inputs are equal to HSI = 16 MHz (if internal clock is used) or HSE = 16 MHz (if HSE bypass mode is used)
- The HSE user clock applied to OSCI\_IN input follows the characteristic specified in [Table 42: High-speed external user clock characteristics](#)
- For maximum current consumption  $V_{DD} = V_{DDA} = 3.6$  V is applied to all supply pins
- For typical current consumption  $V_{DD} = V_{DDA} = 3.0$  V is applied to all supply pins if not specified otherwise

The parameters given in [Table 49](#), [Table 25](#) and [Table 26](#) are derived from tests performed under ambient temperature and  $V_{DD}$  supply voltage conditions summarized in [Table 25](#).

**Electromagnetic Interference (EMI)**

The electromagnetic field emitted by the device are monitored while a simple application is executed (toggling 2 LEDs through the I/O ports). This emission test is compliant with IEC 61967-2 standard which specifies the test board and the pin loading.

**Table 54. EMI characteristics**

Symbol	Parameter	Conditions	Monitored frequency band	Max vs. frequency range at 32 MHz	Unit
S <sub>EMI</sub>	Peak level	V <sub>DD</sub> = 3.6 V, T <sub>A</sub> = 25 °C, LQFP100 package compliant with IEC 61967-2	0.1 to 30 MHz	-7	dBμV
			30 to 130 MHz	14	
			130 MHz to 1 GHz	9	
			EMI Level	2	-

### 6.3.12 I/O current injection characteristics

As a general rule, current injection to the I/O pins, due to external voltage below  $V_{SS}$  or above  $V_{DD}$  (for standard pins) should be avoided during normal product operation. However, in order to give an indication of the robustness of the microcontroller in cases when abnormal injection accidentally happens, susceptibility tests are performed on a sample basis during device characterization.

#### Functional susceptibility to I/O current injection

While a simple application is executed on the device, the device is stressed by injecting current into the I/O pins programmed in floating input mode. While current is injected into the I/O pin, one at a time, the device is checked for functional failures.

The failure is indicated by an out of range parameter: ADC error above a certain limit (higher than 5 LSB TUE), out of conventional limits of induced leakage current on adjacent pins (out of  $-5\ \mu\text{A}/+0\ \mu\text{A}$  range), or other functional failure (for example reset occurrence oscillator frequency deviation).

The test results are given in the [Table 57](#).

**Table 57. I/O current injection susceptibility**

Symbol	Description	Functional susceptibility		Unit
		Negative injection	Positive injection	
$I_{\text{INJ}}$	Injected current on BOOT0	-0	NA	mA
	Injected current on PA0, PA4, PA5, PC15, PH0 and PH1	-5	0	
	Injected current on any other FT, FTf pins	-5 <sup>(1)</sup>	NA	
	Injected current on any other pins	-5 <sup>(1)</sup>	+5	

1. It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative currents.

### 6.3.13 I/O port characteristics

#### General input/output characteristics

Unless otherwise specified, the parameters given in [Table 58](#) are derived from tests performed under the conditions summarized in [Table 25](#). All I/Os are CMOS and TTL compliant.

**Table 58. I/O static characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{IL}$	Input low level voltage	TC, FT, FTf, RST I/Os	-	-	$0.3V_{DD}$	V
		BOOT0 pin	-	-	$0.14V_{DD}^{(1)}$	
$V_{IH}$	Input high level voltage	All I/Os	$0.7 V_{DD}$	-	-	
$V_{hys}$	I/O Schmitt trigger voltage hysteresis <sup>(2)</sup>	Standard I/Os	-	$10\% V_{DD}^{(3)}$	-	
		BOOT0 pin	-	0.01	-	
$I_{lkg}$	Input leakage current <sup>(4)</sup>	$V_{SS} \leq V_{IN} \leq V_{DD}$ All I/Os except for PA11, PA12, BOOT0 and FTf I/Os	-	-	$\pm 50$	nA
		$V_{SS} \leq V_{IN} \leq V_{DD}$ , PA11 and PA12 I/Os	-	-	-50/+250	
		$V_{SS} \leq V_{IN} \leq V_{DD}$ FTf I/Os	-	-	$\pm 100$	
		$V_{DD} \leq V_{IN} \leq 5 V$ All I/Os except for PA11, PA12, BOOT0 and FTf I/Os	-	-	200	nA
		$V_{DD} \leq V_{IN} \leq 5 V$ FTf I/Os	-	-	500	
		$V_{DD} \leq V_{IN} \leq 5 V$ PA11, PA12 and BOOT0	-	-	10	$\mu A$
$R_{PU}$	Weak pull-up equivalent resistor <sup>(5)</sup>	$V_{IN} = V_{SS}$	30	45	60	k $\Omega$
$R_{PD}$	Weak pull-down equivalent resistor <sup>(5)</sup>	$V_{IN} = V_{DD}$	30	45	60	k $\Omega$
$C_{IO}$	I/O pin capacitance	-	-	5	-	pF

1. Guaranteed by characterization.

2. Hysteresis voltage between Schmitt trigger switching levels. Guaranteed by characterization results.

3. With a minimum of 200 mV. Guaranteed by characterization results.

4. The max. value may be exceeded if negative current is injected on adjacent pins.

5. Pull-up and pull-down resistors are designed with a true resistance in series with a switchable PMOS/NMOS. This MOS/NMOS contribution to the series resistance is minimum (~10% order).



**Equation 1:  $R_{AIN}$  max formula**

$$R_{AIN} < \frac{T_S}{f_{ADC} \times C_{ADC} \times \ln(2^{N+2})} - R_{ADC}$$

The simplified formula above ([Equation 1](#)) is used to determine the maximum external impedance allowed for an error below 1/4 of LSB. Here N = 12 (from 12-bit resolution).

**Table 63.  $R_{AIN}$  max for  $f_{ADC} = 16 \text{ MHz}^{(1)}$** 

$T_S$ (cycles)	$t_S$ ( $\mu s$ )	$R_{AIN}$ max for fast channels ( $k\Omega$ )	$R_{AIN}$ max for standard channels ( $k\Omega$ )						
			$V_{DD} > 2.7 \text{ V}$	$V_{DD} > 2.4 \text{ V}$	$V_{DD} > 2.0 \text{ V}$	$V_{DD} > 1.8 \text{ V}$	$V_{DD} > 1.75 \text{ V}$	$V_{DD} > 1.65 \text{ V}$ and $T_A > -10 \text{ }^\circ\text{C}$	$V_{DD} > 1.65 \text{ V}$ and $T_A > 25 \text{ }^\circ\text{C}$
1.5	0.09	0.5	< 0.1	NA	NA	NA	NA	NA	NA
3.5	0.22	1	0.2	< 0.1	NA	NA	NA	NA	NA
7.5	0.47	2.5	1.7	1.5	< 0.1	NA	NA	NA	NA
12.5	0.78	4	3.2	3	1	NA	NA	NA	NA
19.5	1.22	6.5	5.7	5.5	3.5	NA	NA	NA	< 0.1
39.5	2.47	13	12.2	12	10	NA	NA	NA	5
79.5	4.97	27	26.2	26	24	< 0.1	NA	NA	19
160.5	10.03	50	49.2	49	47	32	< 0.1	< 0.1	42

1. Guaranteed by design.

**Table 64. ADC accuracy<sup>(1)(2)(3)</sup>**

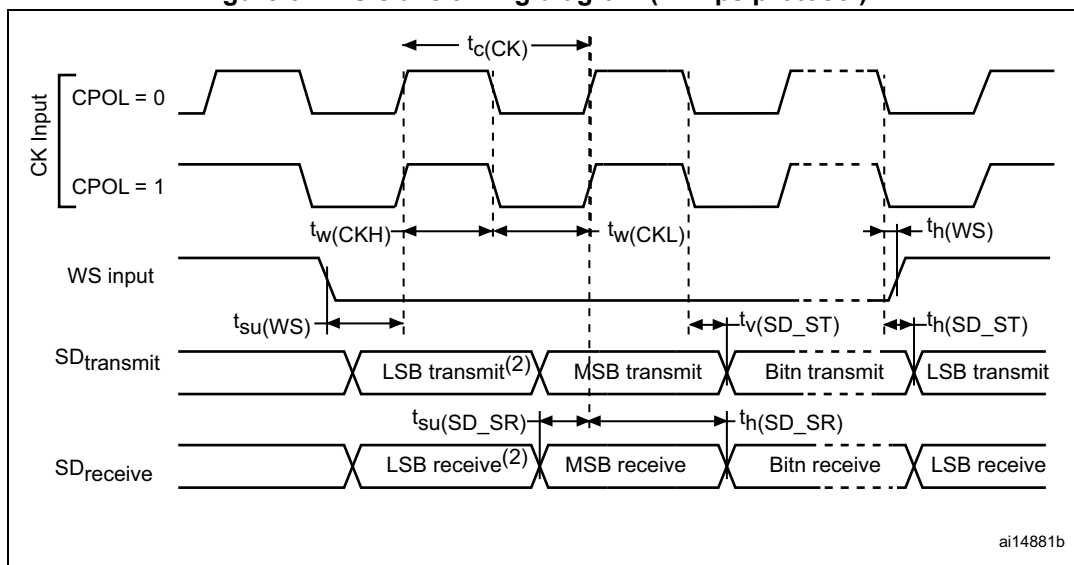
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
ET	Total unadjusted error	$1.65 \text{ V} < V_{DDA} = V_{REF+} < 3.6 \text{ V}$ , range 1/2/3	-	2	4	LSB
EO	Offset error		-	1	2.5	
EG	Gain error		-	1	2	
EL	Integral linearity error		-	1.5	2.5	
ED	Differential linearity error		-	1	1.5	
ENOB	Effective number of bits		10.2	11	-	bits
	Effective number of bits (16-bit mode oversampling with ratio =256) <sup>(4)</sup>		11.3	12.1	-	
SINAD	Signal-to-noise distortion		63	69	-	dB
SNR	Signal-to-noise ratio		63	69	-	
	Signal-to-noise ratio (16-bit mode oversampling with ratio =256) <sup>(4)</sup>		70	76	-	
THD	Total harmonic distortion		-	-85	-73	

Table 73. SPI characteristics in voltage Range 2 <sup>(1)</sup>

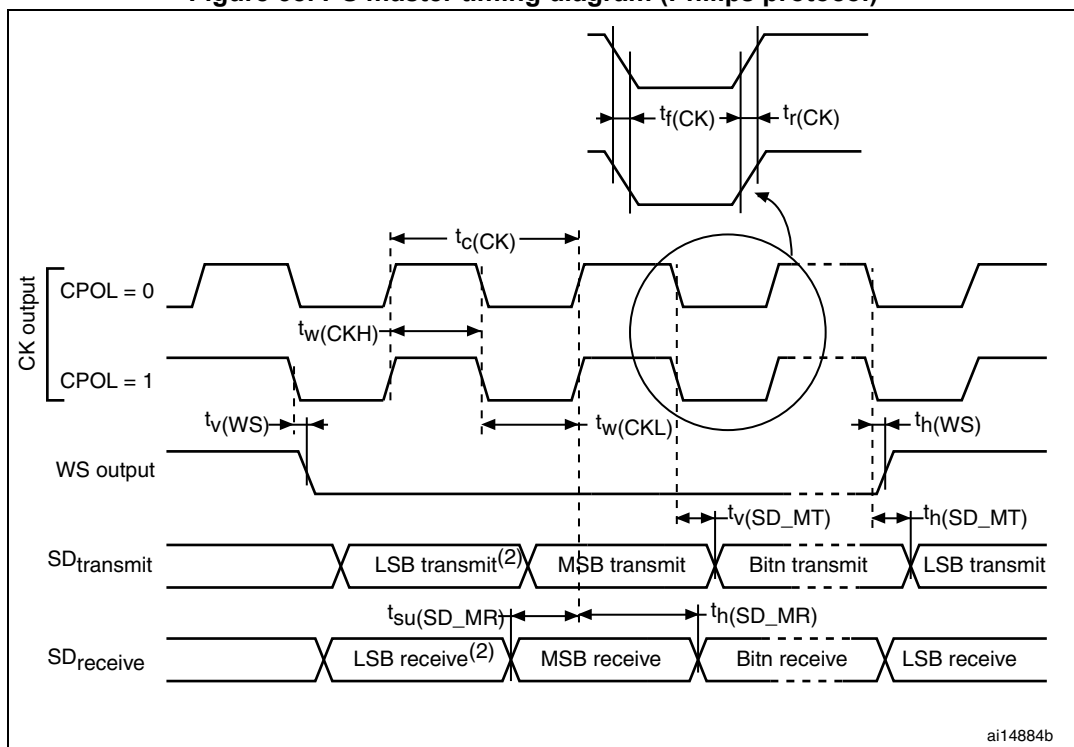
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$f_{SCK}$ $1/t_{c(SCK)}$	SPI clock frequency	Master mode	-	-	8	MHz
		Slave mode Transmitter $1.65 < V_{DD} < 3.6V$			8	
		Slave mode Transmitter $2.7 < V_{DD} < 3.6V$			8 <sup>(2)</sup>	
$Duty_{(SCK)}$	Duty cycle of SPI clock frequency	Slave mode	30	50	70	%
$t_{su(NSS)}$	NSS setup time	Slave mode, SPI presc = 2	$4 \cdot T_{pclk}$	-	-	ns
$t_{h(NSS)}$	NSS hold time	Slave mode, SPI presc = 2	$2 \cdot T_{pclk}$	-	-	
$t_{w(SCKH)}$ $t_{w(SCKL)}$	SCK high and low time	Master mode	$T_{pclk} - 2$	$T_{pclk}$	$T_{pclk} + 2$	
$t_{su(MI)}$	Data input setup time	Master mode	0	-	-	
$t_{su(SI)}$		Slave mode	3	-	-	
$t_{h(MI)}$	Data input hold time	Master mode	11	-	-	
$t_{h(SI)}$		Slave mode	4.5	-	-	
$t_{a(SO)}$	Data output access time	Slave mode	18	-	52	
$t_{dis(SO)}$	Data output disable time	Slave mode	12	-	42	
$t_{v(SO)}$	Data output valid time	Slave mode	-	20	56.5	
$t_{v(MO)}$		Master mode	-	5	9	
$t_{h(SO)}$	Data output hold time	Slave mode	13	-	-	
$t_{h(MO)}$		Master mode	3	-	-	

1. Guaranteed by characterization results.

2. The maximum SPI clock frequency in slave transmitter mode is determined by the sum of  $t_{v(SO)}$  and  $t_{su(MI)}$  which has to fit into SCK low or high phase preceding the SCK sampling edge. This value can be achieved when the SPI communicates with a master having  $t_{su(MI)} = 0$  while  $Duty_{(SCK)} = 50\%$ .

Figure 37. I<sup>2</sup>S slave timing diagram (Philips protocol)<sup>(1)</sup>

1. Measurement points are done at CMOS levels:  $0.3 \times V_{DD}$  and  $0.7 \times V_{DD}$ .
2. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.

Figure 38. I<sup>2</sup>S master timing diagram (Philips protocol)<sup>(1)</sup>

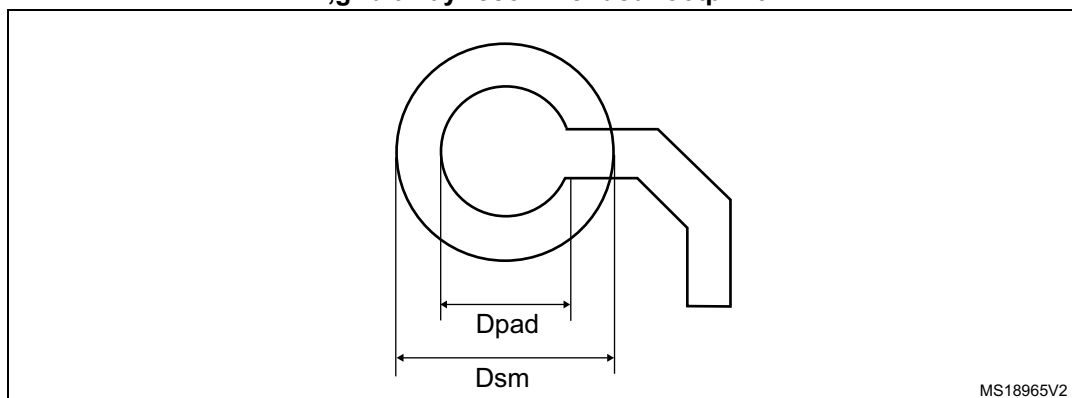
1. Guaranteed by characterization results.
2. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.

**Table 80. TFBGA64 – 64-ball, 5 x 5 mm, 0.5 mm pitch, thin profile fine pitch ball grid array package mechanical data (continued)**

Symbol	millimeters			inches <sup>(1)</sup>		
	Min	Typ	Max	Min	Typ	Max
e	-	0.500	-	-	0.0197	-
F	-	0.750	-	-	0.0295	-
ddd	-	-	0.080	-	-	0.0031
eee	-	-	0.150	-	-	0.0059
fff	-	-	0.050	-	-	0.0020

1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 48. TFBGA64 – 64-ball, 5 x 5 mm, 0.5 mm pitch, thin profile fine pitch ball grid array recommended footprint**



**Table 81. TFBGA64 recommended PCB design rules (0.5 mm pitch BGA)**

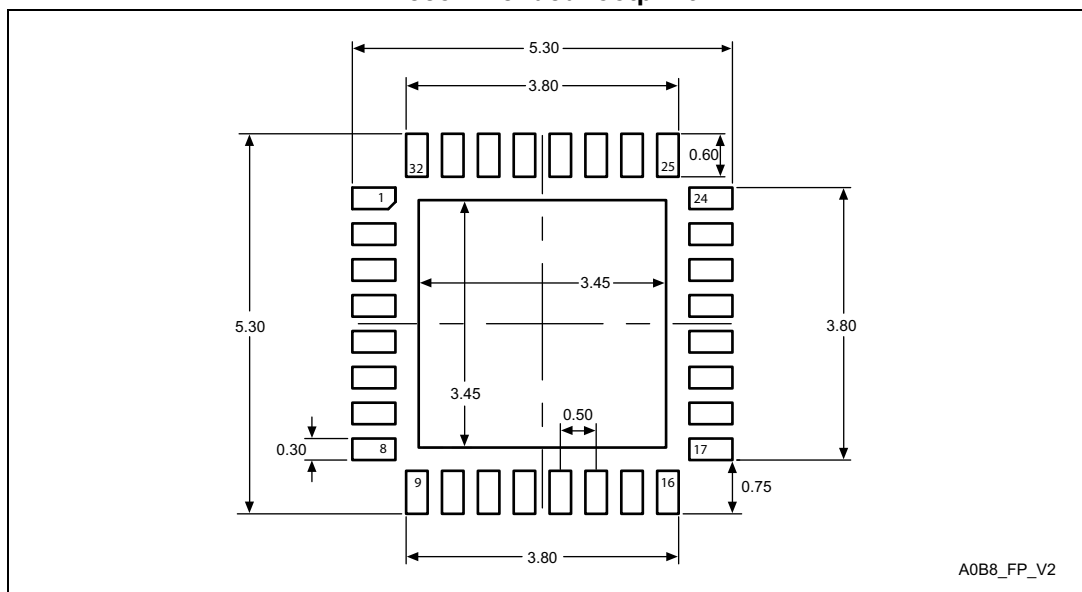
Dimension	Recommended values
Pitch	0.5
Dpad	0.27 mm
Dsm	0.35 mm typ. (depends on the soldermask registration tolerance)
Solder paste	0.27 mm aperture diameter.

**Note:** *Non solder mask defined (NSMD) pads are recommended.  
4 to 6 mils solder paste screen printing process.*

**Table 86. UFQFPN32 - 32-pin, 5x5 mm, 0.5 mm pitch ultra thin fine pitch quad flat package mechanical data**

Symbol	millimeters			inches <sup>(1)</sup>		
	Min	Typ	Max	Min	Typ	Max
A	0.500	0.550	0.600	0.0197	0.0217	0.0236
A1	0.000	0.020	0.050	0.0000	0.0008	0.0020
A3	-	0.152	-	-	0.0060	-
b	0.180	0.230	0.280	0.0071	0.0091	0.0110
D	4.900	5.000	5.100	0.1929	0.1969	0.2008
D1	3.400	3.500	3.600	0.1339	0.1378	0.1417
D2	3.400	3.500	3.600	0.1339	0.1378	0.1417
E	4.900	5.000	5.100	0.1929	0.1969	0.2008
E1	3.400	3.500	3.600	0.1339	0.1378	0.1417
E2	3.400	3.500	3.600	0.1339	0.1378	0.1417
e	-	0.500	-	-	0.0197	-
L	0.300	0.400	0.500	0.0118	0.0157	0.0197
ddd	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 60. UFQFPN32 - 32-pin, 5x5 mm, 0.5 mm pitch ultra thin fine pitch quad flat recommended footprint**

1. Dimensions are expressed in millimeters.